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Renesas Technology Corp. Customer Support Dept. April 1, 2003



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2SB1002

Silicon PNP Epitaxial



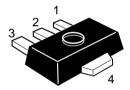
ADE-208-1035 (Z) 1st. Edition Mar. 2001

Application

- Low frequency power amplifier
- Complementary pair with 2SD1368

Outline

UPAK



- 1. Base
- 2. Collector
- 3. Emitter
- 4. Collector (Flange)

2SB1002

Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit	
Collector to base voltage	V_{CBO}	V _{CBO} -70		
Collector to emitter voltage	V_{CEO}	- 50	V	
Emitter to base voltage	V_{EBO}	-6	V	
Collector current	I _c	-1	А	
Collector peak current	i _{C(peak)} *1	-1.5	Α	
Collector power dissipation	P _C *2	1	W	
Junction temperature	Tj	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

Notes: 1. PW ≤ 10 ms, Duty cycle ≤ 20%

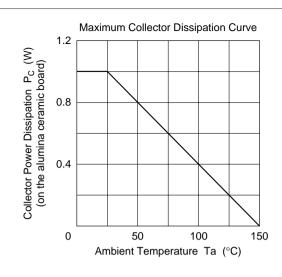
2. Value on the alumina ceramic board (12.5 \times 20 \times 0.7 mm)

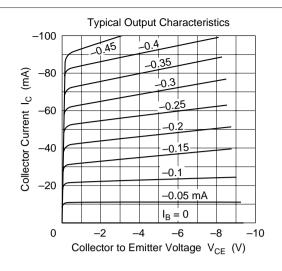
Electrical Characteristics (Ta = 25°C)

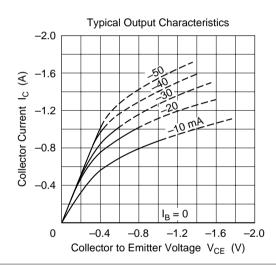
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	-70	_	_	V	$I_{c} = -10 \ \mu A, \ I_{E} = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	-50	_	_	V	$I_{C} = -1 \text{ mA}, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	-6	_	_	V	$I_{E} = -10 \mu A, I_{C} = 0$
Collector cutoff current	I _{CBO}	_	_	-0.1	μΑ	$V_{CB} = -50 \text{ V}, I_{E} = 0$
Emitter cutoff current	I _{EBO}	_	_	-0.1	μΑ	$V_{EB} = -4 \text{ V}, I_{C} = 0$
DC current transfer ratio	h _{FE} *1	100	_	320		$V_{CE} = -2 \text{ V}, I_{C} = -0.1 \text{ A}$
Collector to emitter saturation voltage	V _{CE(sat)}	_	_	-0.6	V	$I_{\rm C} = -1$ A, $I_{\rm B} = -0.1$ A (Pulse test)
Base to emitter saturation voltage	$V_{BE(sat)}$	_	_	-1.2	V	$I_{\rm C} = -1$ A, $I_{\rm B} = -0.1$ A (Pulse test)
Gain bandwidth product	f _T	_	150	_	MHz	$V_{CE} = -2 \text{ V},$ $I_{C} = -10 \text{ mA (Pulse test)}$
Collector output capacitance	Cob	_	35	_	pF	$V_{CB} = -10 \text{ V}, I_{E} = 0,$ f = 1 MHz

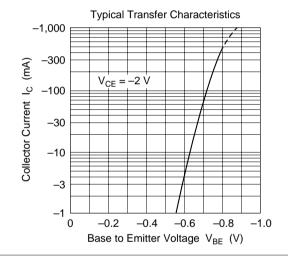
Note: 1. The 2SB1002 is grouped by h_{FE} as follows.

Mark	СН	CJ
h _{FE}	100 to 200	160 to 320

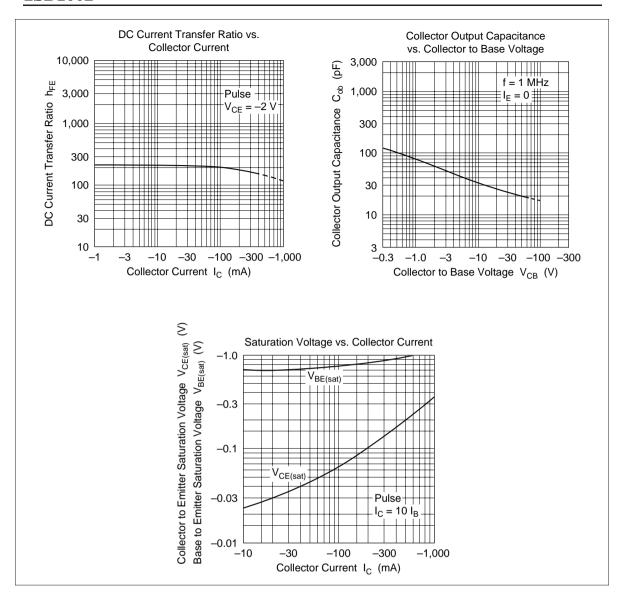




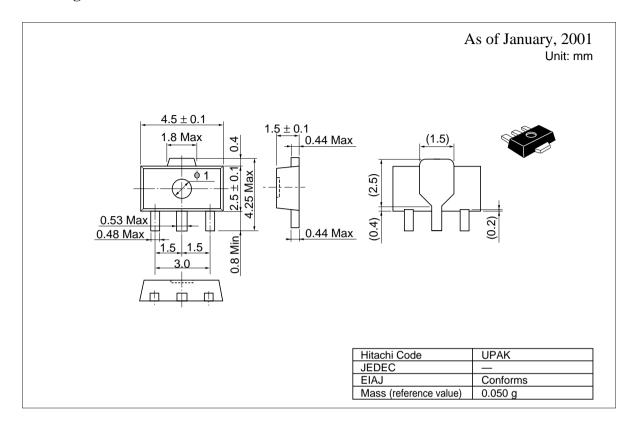




2SB1002



Package Dimensions



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